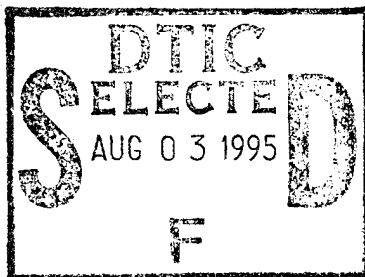


**Complementary 2-D MESFET for
Low Power Electronics**

Interim Report # 4

**Air Force SBIR Phase I
Contract Number: F33615-95-C-1679**

July 31, 1995



Delivered To:

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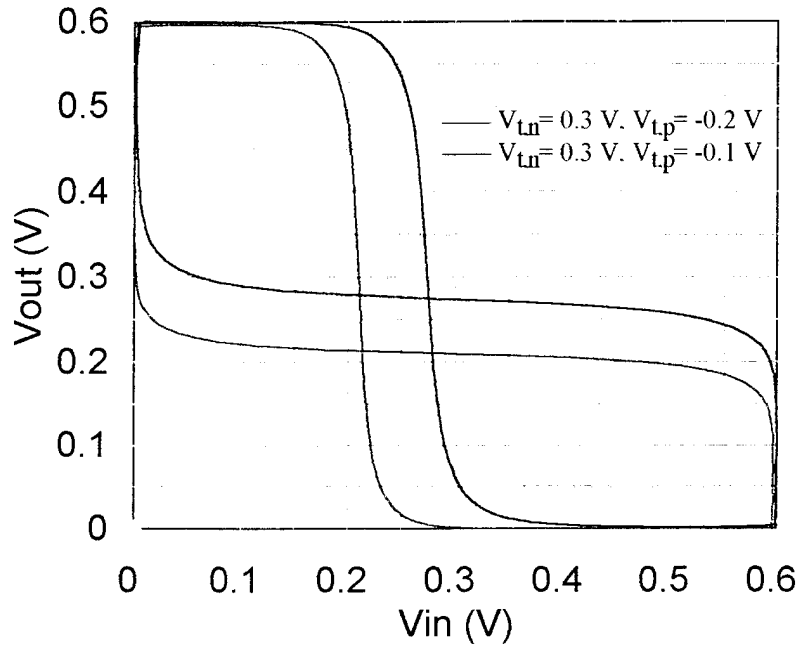


Fig. 1. Complementary 2-D MESFET DC inverter characteristics for two different p -channel threshold voltages at $V_{DD} = 0.6$ V. Both inverters have noise margins of above 0.2 V and voltage gains of about 10.

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